

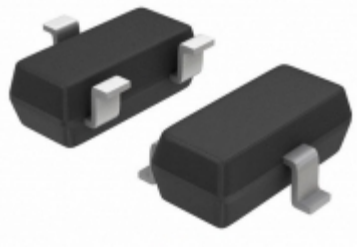


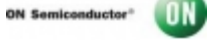
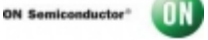






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|---|---|
|  | <h2 style="color: red;">NVTR4502PT1G</h2> |
| | <p>Hersteller-Teilenummer: NVTR4502PT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 30V 1.95A SOT23</p> <hr/> <p>Datenblätter:  NVTR4502PT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 259127 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|---|
| Teilenummer | NVTR4502PT1G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET P-CH 30V 1.95A SOT23 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 259127 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-236-3, SC-59, SOT-23-3 |
| Supplier Device-Gehäuse | SOT-23-3 (TO-236) |
| Verlustleistung (max) | 400mW (Tj) |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 1.13A (Ta) |
| Rds On (Max) @ Id, Vgs | 200 mOhm @ 1.95A, 10V |
| VGS (th) (Max) @ Id | 3V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 10nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 200pF @ 15V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |



NVTR4502PT1G ist neu im Original, Suche NVTR4502PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVTR4502PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVTR4502PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|---|---|
|  <p>NVTP2955G AMI Semiconductor / ON Semiconductor MOSFET 60V 12A 196</p> |  <p>NVTJD4401NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 0.63A SC-88</p> |  <p>NVTJD4105CT1G AMI Semiconductor / ON Semiconductor MOSFET 20V 0.63A SC-88</p> |  <p>NVTR01P02T O O SOT-23</p> |
|  <p>NVTJD4158CT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 0.88A SC-88</p> |  <p>NVTR4502PT O NVTR4502PT O</p> |  <p>NVTR4503NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 1.5A SOT23</p> |  <p>NVTR01P02LT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 1.3A SOT23</p> |

heiße Teile

Mehr

| | | | | |
|--|---|--|---|--|
|  08052U8R2DAT2A |  A50L-1-0221 |  AD1988BJSTZ |  AP2317R-3.3TRE1 |  AP501-G1 |
|  B82496C3470J |  BCW60BE-6327 |  BL8506-33CRM |  CBT3257DS |  CGA2B2X5R1E153K050BA |
|  CGA9N2X7R1E156M230KA |  CM2305-SR-L |  CSTCE12M2G55-R0 |  DLW5ASN252SQ2L |  DS52-0005-TR |
|  EL4581CN |  F1857RD400 |  GQM2195C2E560FB12J |  GRM1555C1H6R6BA01D |  GRT155C80J105ME01D |
|  HCPL2611 |  HEF4022BP |  HLMP1719 |  IRKD71/12 |  IRL2203NPBF |
|  ISL55001IBZ |  ISP1106WTS |  K1351VC650 |  KLM4G2DEJE-A001 |  LMK04808BISQ |
|  LOC110-F |  LT1763IS8-5#TRPBF |  LT3493ASE6#PBF |  MBRB2535CT-G-T4 |  MJYD-JL-20/380 |
|  NVTR4502PT |  NVTR4503NT1G |  PC3SH21YFZCF |  PM52AUBX060-1 |  SC618MLTRT |
|  SPS03N60C3 |  T529N10TOF |  TBU-PK075-100-WH |  TLV7111233DSER |  TS9002IM8T |
|  VI-254-31 |  VS-20L15TSPBF |  W8405ZC100 |  XC6209B122MR |  ZS1R54812 |

Contact us: Info@Y-IC.com

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